

Features

- Low Cost
- Very High Capacitance Ratio from 1 to 8 Volts
- Surface Mount Package
- High Quality Factor
- Useful for Battery Applications
- SPC Monitored Ion Implantation for Excellent C-V Repeatability
- Available in Tape and Reel
- Lead-Free
- RoHS* Compliant

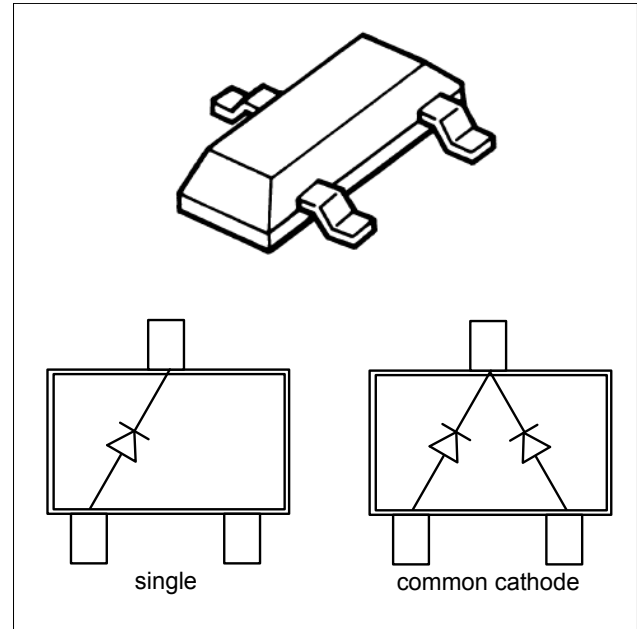
Description

The MAVR-000079 - 83 series of silicon hyperabrupt junction tuning varactors is produced with ion implantation and advanced epitaxial growth techniques. These diodes have thermal oxide passivation, and feature very high capacitance ratio and quality factor. They are well suited for use from the sub-HF through UHF frequency range. The standard capacitance tolerance is $\pm 10\%$, with tighter tolerances available. Capacitance matching at one or more bias voltages is also available. These diodes are offered with standard Sn/Pb plating, as well as 100% matte Sn plating.

Applications

This series of hyperabrupt junction tuning varactors is suggested for usage where a large frequency change is required with only a small change in tuning voltage. This series is appropriate for usage in wide band voltage controlled oscillators and voltage controlled filters which require the largest rate of change of capacitance with voltage. The large change in capacitance from 1 to 8 volts makes them very attractive for battery operated or other systems with limited available control voltage. This varactor series can be used in VCO's and VTF's from approximately 100 KHz through the UHF frequency band.

SOT-23 (ODS-287)



Ordering Information

Part Number	Single Configuration
MAVR-000079-0287FT	tape and reel
MAVR-000080-0287AT	tape and reel
MAVR-000081-0287AT	tape and reel
MAVR-000082-0287AT	tape and reel
MAVR-000083-0287AT	tape and reel

Surface Mount Hyperabrupt Wide-Band Tuning Varactors

Rev. V8

Electrical Specifications @ $T_A = +25^\circ\text{C}$

Breakdown Voltage @ $I_R = 10\text{ mA}$, $V_b = 12\text{ V}$ Minimum

Reverse Leakage Current @ $V_R = 10\text{ V}$, $I_R = 100\text{ nA}$ Maximum

Temperature Coefficient of Capacitance @ $V_R = 8\text{ V}$, $TCC = 400\text{ ppm}/^\circ\text{C}$ Typical

Part #	Ct @ 1 MHz (pF)					Capacitance Ratio @ 1 MHz Ct _{1V} /Ct _{8V}	Q @ 50 MHz
	V _R = 1 V	V _R = 2.5 V		V _R = 4 V	V _R = 8 V	V _R = 1 V / 8 V	V _R = 4 V
	Min.	Min.	Max.	Max	Max.	Typ.	Typ.
MAVR-000079-0287FT	87.4	48.7	59.5	27.3	11.8	9.1	80
MAVR-000080-0287AT	40.0	22.3	27.3	13.1	5.5	8.9	150
MAVR-000081-0287AT	16.2	9.1	11.1	5.2	2.4	8.5	300
MAVR-000082-0287AT	11.5	6.6	8.0	3.8	1.8	8.2	350
MAVR-000083-0287AT	7.9	4.5	5.5	2.6	1.3	7.8	450

Absolute Maximum Ratings^{1,2}

Parameter	Absolute Maximum
Reverse Voltage	12 V
Forward Current	50 mA
Power Dissipation	50 mW @ +25°C
Operating Temperature	-65°C to +125°C
Storage Temperature	-65°C to +125°C

1. Operation of this device above any one of these parameters may cause permanent damage.
2. Please refer to application note M538 for surface mounting instructions.

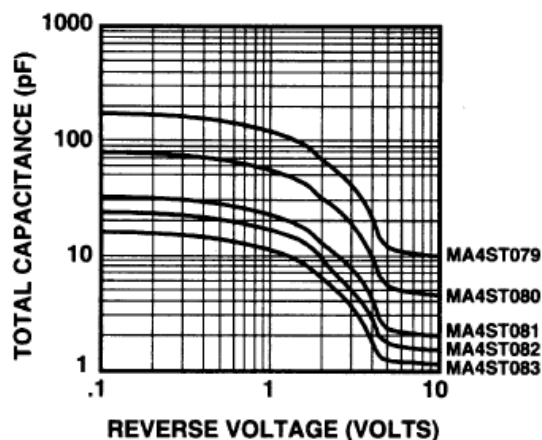
Handling Procedures

Please observe the following precautions to avoid damage:

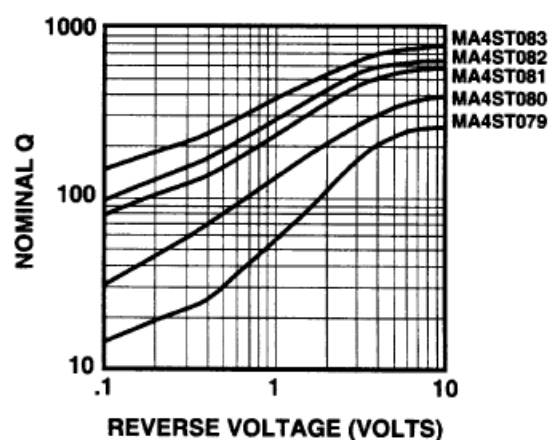
Static Sensitivity

These electronic devices are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these devices.

Total Capacitance vs. Reverse Voltage



Nominal Q vs. Reverse Voltage



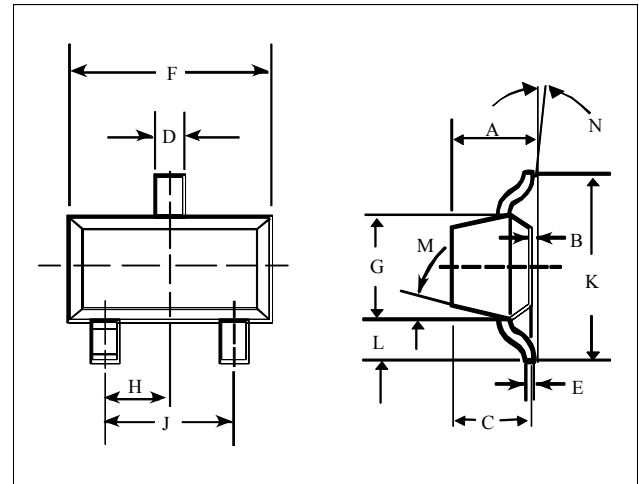
Mounting Information

The illustration indicates the recommended mounting pad configuration for the SOT-23 package. Solder paste containing flux should be screened onto the pads to a thickness of 0.005 - 0.007 inches. The plastic package is placed in position, firmly adhering to the solder paste.

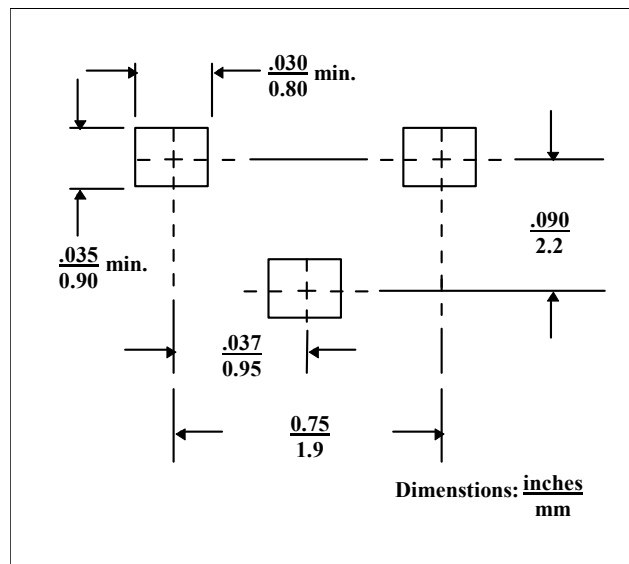
Permanent attachment is performed by a reflow soldering procedure during which the tab temperature does not exceed +275°C and the body temperature does not exceed +250°C, for standard models and +260°C for the RoHS compliant devices.

Please refer to Application Note M538 for surface mounting instructions.

SOT-23 (Case Style 287)



SOT-23



SOT-23 (Case Style 287)

DIM.	INCHES		MILLIMETERS	
	MIN.	MAX.	MIN.	MAX.
A	—	0.048	—	1.22
B	—	0.008	—	0.20
C	—	0.040	—	1.00
D	0.013	0.020	0.35	0.50
E	0.003	0.006	0.08	0.15
F	0.110	0.119	2.80	3.00
G	0.047	0.056	1.20	1.40
H	0.037 typical		0.95 typical	
J	0.075 typical		1.90 typical	
K	—	0.103	—	2.60
L	—	0.024	—	0.60
DIM.	GRADIENT			
M	10° max.			
N	2° . . . 30°			